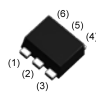
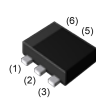


Parameter	Tr1 and Tr2
V_{CEO}	50V
I_C	100mA

●Outline

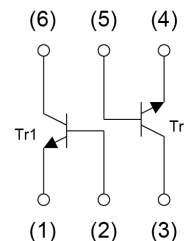
VMT6  VT6X2	EMT6  EMX52 (SC-107C)
---	--

●Features

- 1) General Purpose.
- 2) Two 2SCR523 chips in one package.
- 3) Transistor elements are independent, eliminating interface.
- 4) Mounting cost and area can be cut in half.
- 5) Lead Free/RoHS Compliant.

●Inner circuit

- (1) Tr1 Emitter
- (2) Tr1 Base
- (3) Tr2 Collector
- (4) Tr2 Emitter
- (5) Tr2 Base
- (6) Tr1 Collector



●Application

Switching, LED driver

●Packaging specifications

Part No.	Package	Package size	Taping code	Reel size (mm)	Tape width (mm)	Basic ordering unit.(pcs)	Marking
VT6X2	VMT6	1212	T2R	180	8	8000	X2
EMX52	EMT6	1616	T2R	180	8	8000	X52

● **Absolute maximum ratings** ($T_a = 25^\circ\text{C}$)

<For Tr1 and Tr2 in common>

Parameter		Symbol	Values	Unit
Collector-base voltage		V_{CBO}	50	V
Collector-emitter voltage		V_{CEO}	50	V
Emitter-base voltage		V_{EBO}	5	V
Collector current		I_{C}	100	mA
		I_{CP}^{*1}	200	mA
Power dissipation	VT6X2	P_{D}^{*2*3}	150	mW
	EMX52		150	
Junction temperature		T_{j}	150	$^\circ\text{C}$
Range of storage temperature		T_{stg}	-55 to +150	$^\circ\text{C}$

● **Electrical characteristics** ($T_a = 25^\circ\text{C}$)

<For Tr1 and Tr2 in common>

Parameter	Symbol	Conditions	Values			Unit
			Min.	Typ.	Max.	
Collector-base breakdown voltage	BV_{CBO}	$I_{\text{C}} = 50\mu\text{A}$	50	-	-	V
Collector-emitter breakdown voltage	BV_{CEO}	$I_{\text{C}} = 1\text{mA}$	50	-	-	V
Emitter-base breakdown voltage	BV_{EBO}	$I_{\text{E}} = 50\mu\text{A}$	5	-	-	V
Collector cut-off current	I_{CBO}	$V_{\text{CB}} = 50\text{V}$	-	-	0.1	μA
Emitter cut-off current	I_{EBO}	$V_{\text{EB}} = 5\text{V}$	-	-	0.1	μA
Collector-emitter saturation voltage	$V_{\text{CE(sat)}}$	$I_{\text{C}} = 50\text{mA}, I_{\text{B}} = 5\text{mA}$	-	0.10	0.30	V
DC current gain	h_{FE}	$V_{\text{CE}} = 6\text{V}, I_{\text{C}} = 1\text{mA}$	120	-	560	-
Transition frequency	f_{T}	$V_{\text{CE}} = 10\text{V}, I_{\text{E}} = -10\text{mA}, f = 100\text{MHz}$	-	350	-	MHz
Output capacitance	C_{ob}	$V_{\text{CB}} = 10\text{V}, I_{\text{E}} = 0\text{A}, f = 1\text{MHz}$	-	1.6	-	pF

*1 $P_w=1\text{ms}$ Single Pulse

*2 Each terminal mounted on a reference footprint

*3 120mW per element must not be exceeded.

● **Electrical characteristic curves (Ta=25°C)**
 <For Tr1 and Tr2 in common>

Fig.1 Grounded Emitter Propagation Characteristics

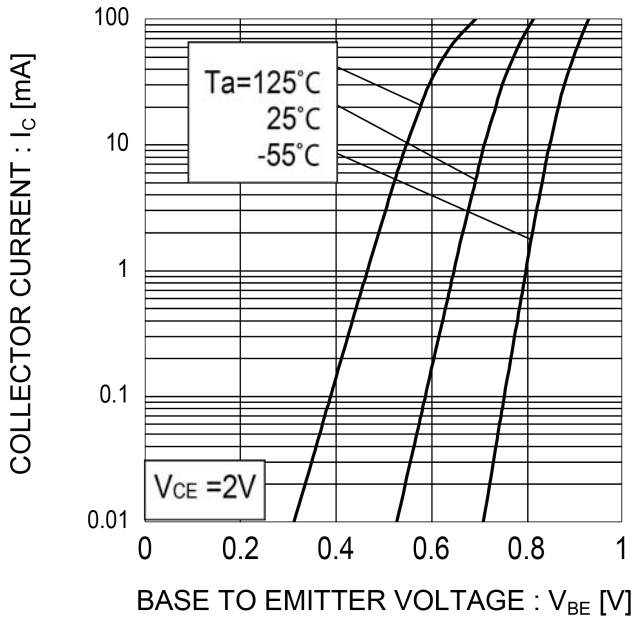


Fig.2 Typical Output Characteristics

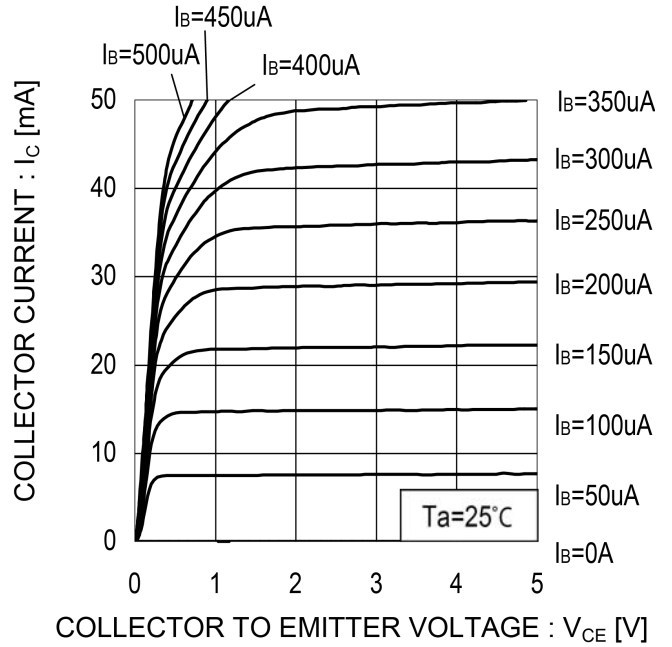


Fig.3 DC Current Gain vs. Collector Current(I)

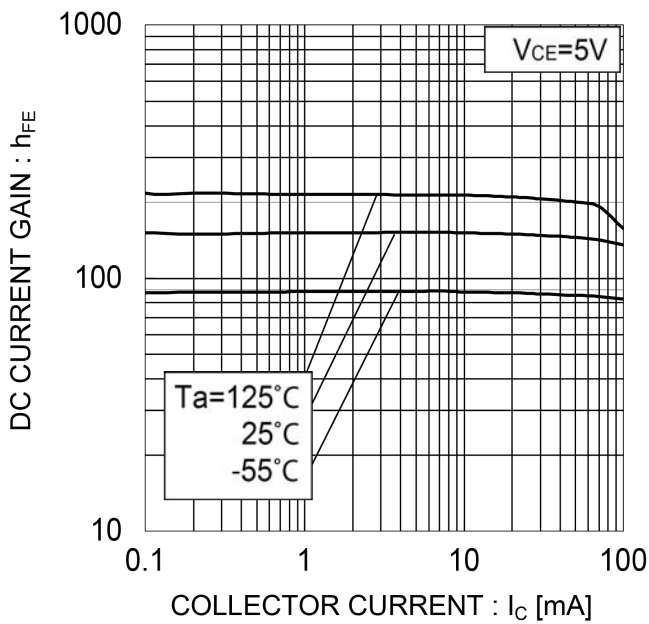
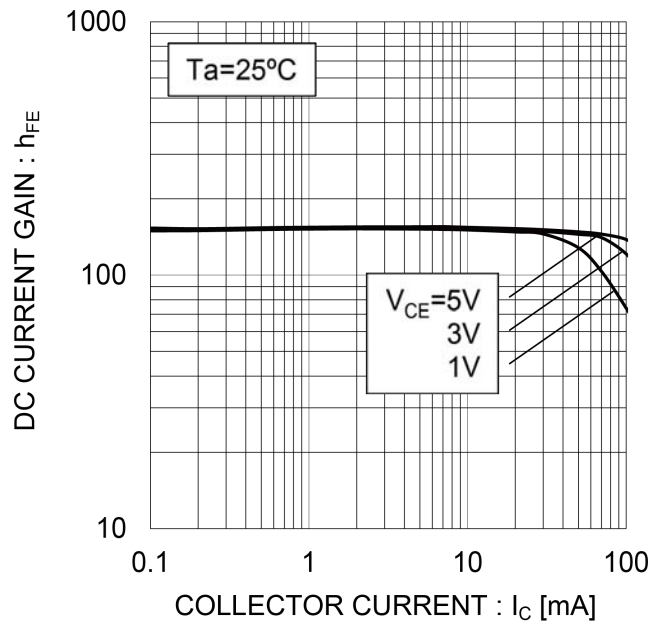


Fig.4 DC Current Gain vs. Collector Current(II)



● **Electrical characteristic curves** ($T_a=25^\circ\text{C}$)

<For Tr1 and Tr2 in common>

Fig.5 Collector-Emitter Saturation Voltage vs. Collector Current(I)

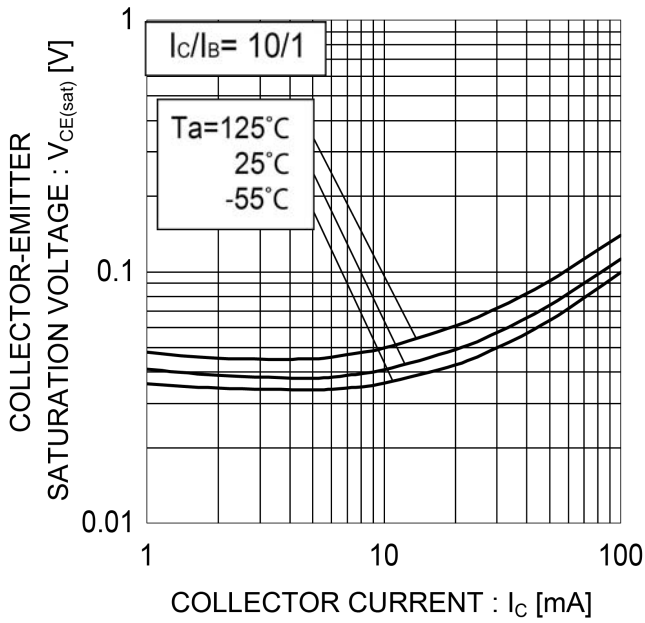


Fig.6 Collector-Emitter Saturation Voltage vs. Collector Current(II)

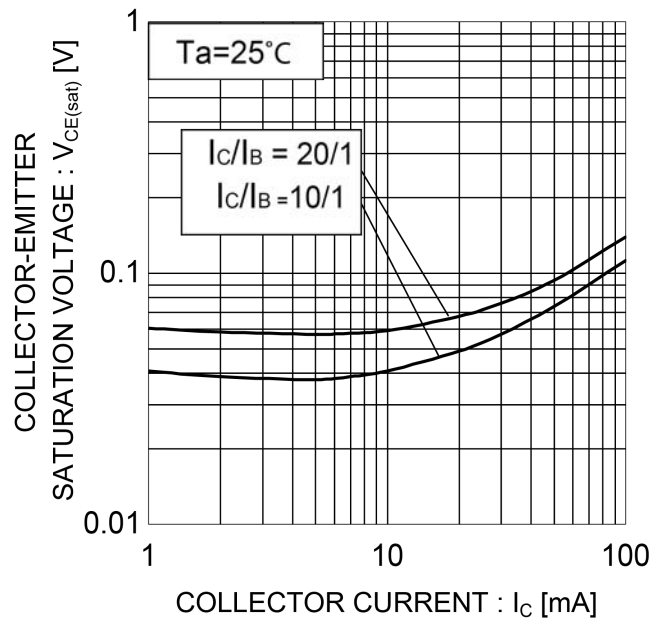


Fig.7 Base-Emitter Saturation Voltage vs. Collector Current

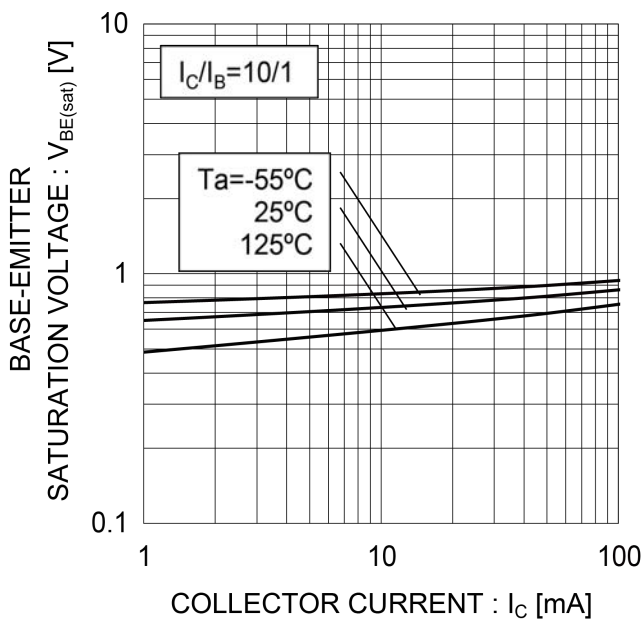
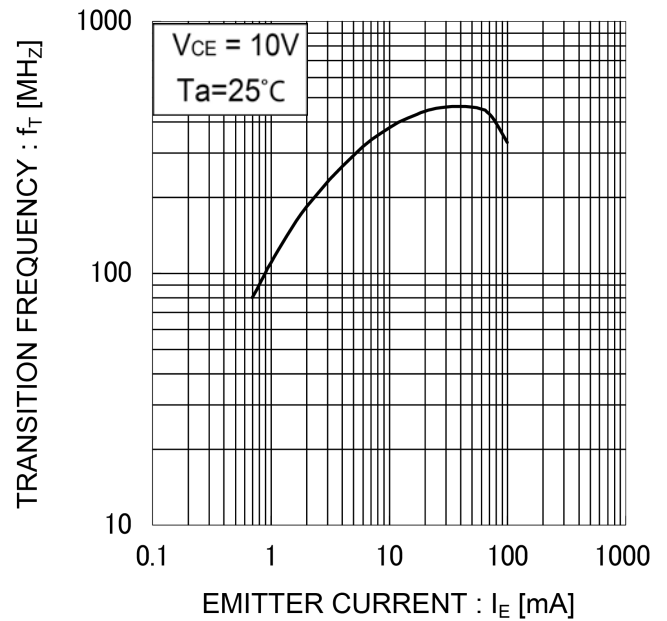


Fig.8 Gain Bandwidth Product vs. Emitter Current



● **Electrical characteristic curves** ($T_a = 25^\circ\text{C}$)

<For Tr1 and Tr2 in common>

Fig.9 Emitter input capacitance vs. Emitter-Base Voltage Collector output capacitance

vs.

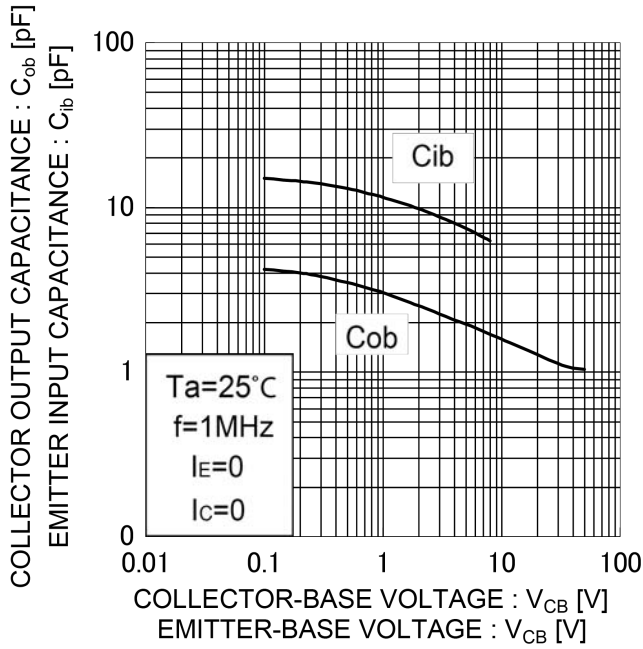
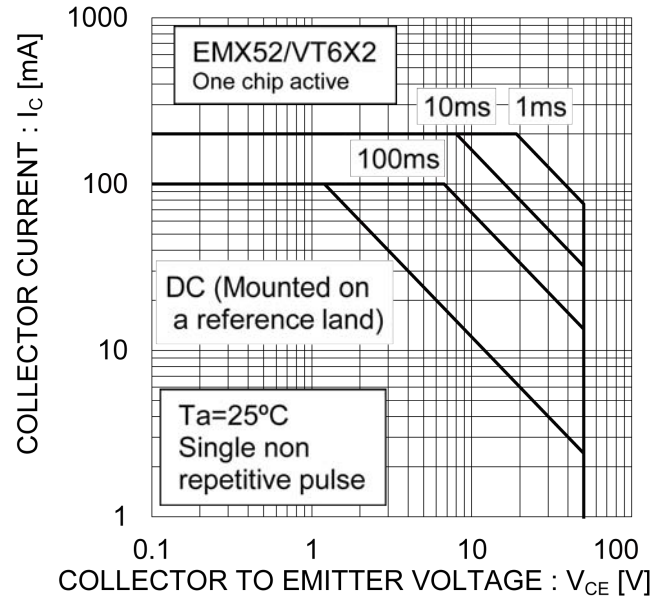
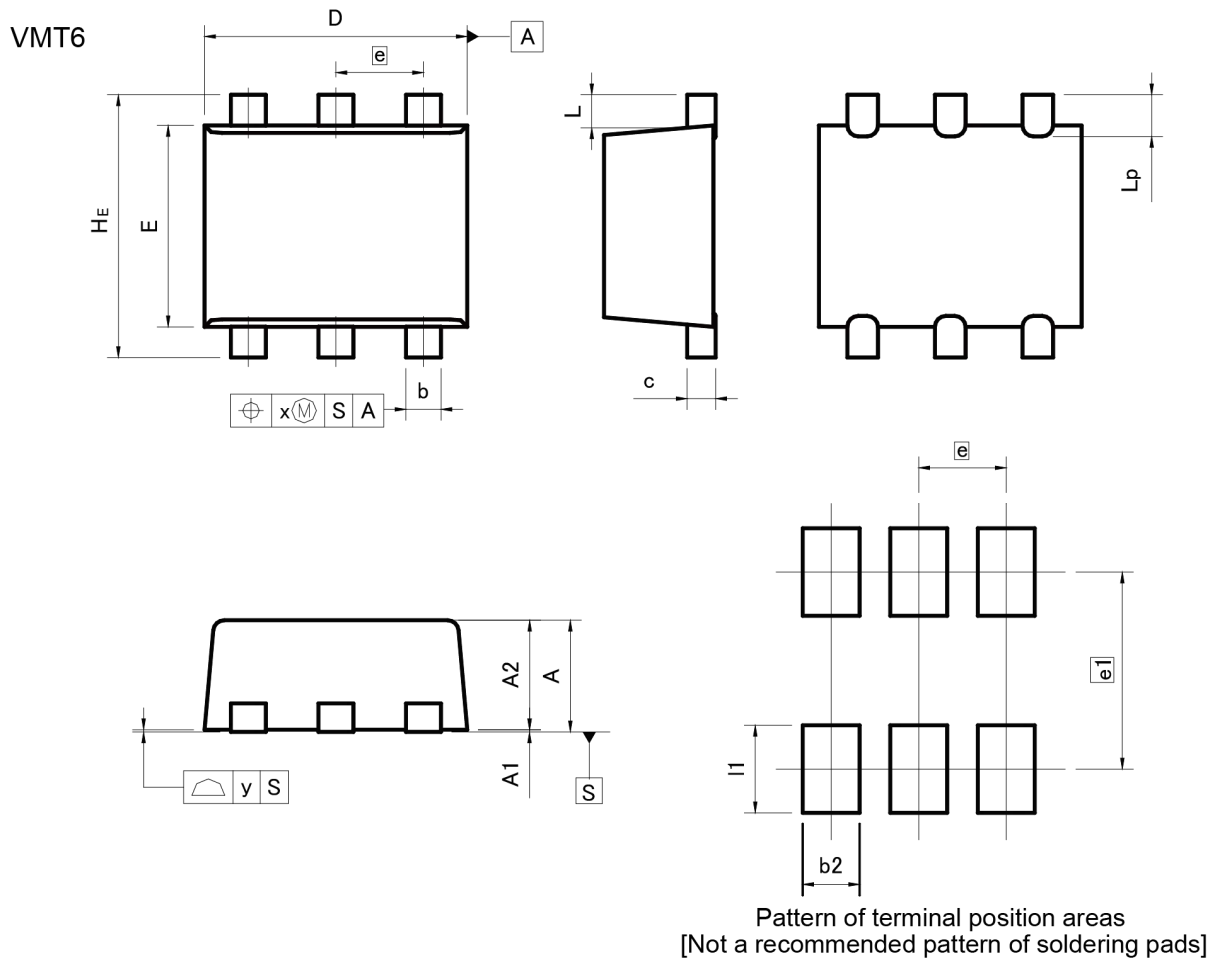


Fig.10 Safe Operating Area



●Dimensions

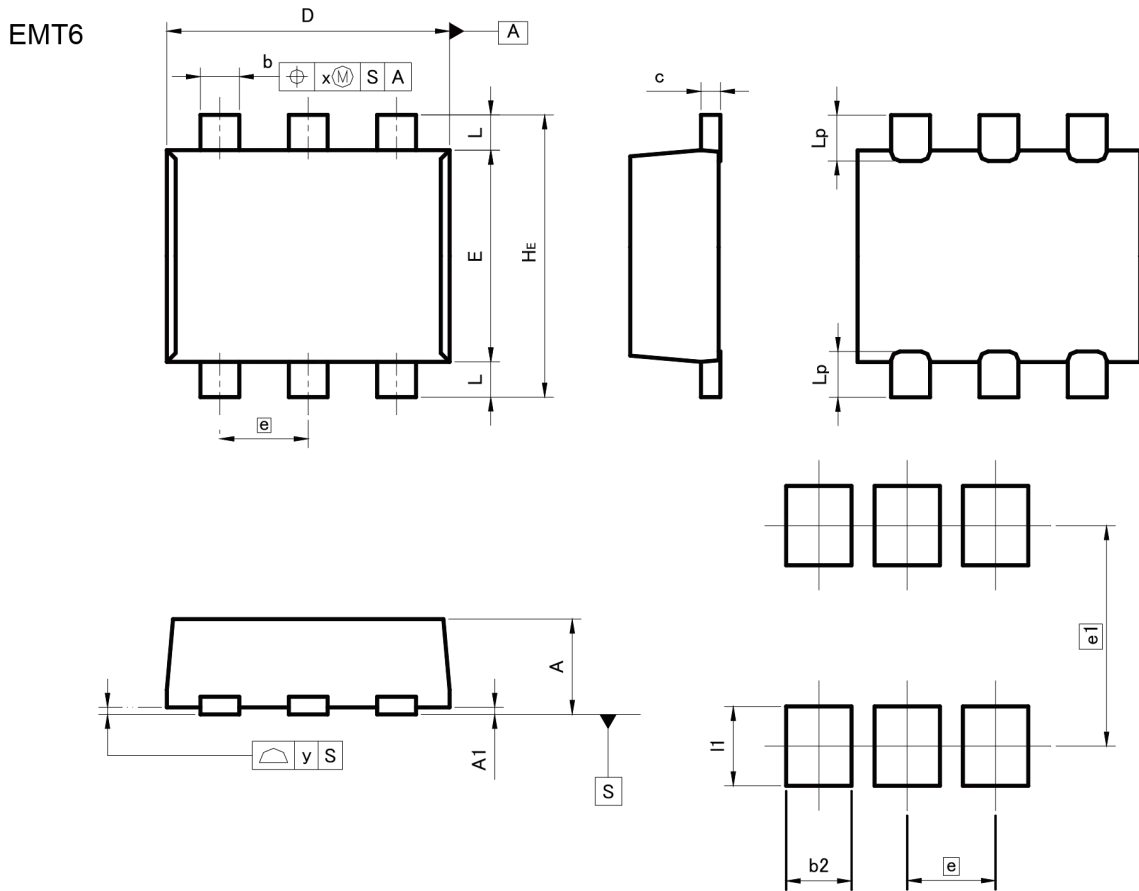


DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	0.42	0.62	0.017	0.024
A1	0.00	0.05	0.000	0.002
A2	0.40	0.60	0.016	0.024
b	0.11	0.21	0.004	0.008
c	0.08	0.18	0.003	0.007
D	1.10	1.30	0.043	0.051
E	0.82	1.02	0.032	0.04
e	0.40		0.016	
HE	1.10	1.30	0.043	0.051
L	0.14		0.006	
Lp	0.10	0.30	0.004	0.012
x	-	0.05	-	0.002
y	-	0.10	-	0.004

DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
b2	-	0.26	-	0.010
e1	0.90		0.035	
l1	-	0.40	-	0.016

Dimension in mm/inches

●Dimensions



Pattern of terminal position areas
[Not a recommended pattern of soldering pads]

DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	0.45	0.55	0.018	0.022
A1	0.00	0.10	0.000	0.004
b	0.17	0.27	0.007	0.011
c	0.08	0.18	0.003	0.007
D	1.50	1.70	0.059	0.067
E	1.10	1.30	0.043	0.051
e	0.50		0.020	
HE	1.50	1.70	0.059	0.067
L	0.10	0.30	0.004	0.012
Lp	-	0.35	-	0.014
x	-	0.10	-	0.004
y	-	0.10	-	0.004
DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
b2	-	0.37	-	0.015
e1	1.25		0.049	
I1	-	0.45	-	0.018

Dimension in mm/inches

Notes

- 1) The information contained herein is subject to change without notice.
- 2) Before you use our Products, please contact our sales representative and verify the latest specifications :
- 3) Although ROHM is continuously working to improve product reliability and quality, semiconductors can break down and malfunction due to various factors.
Therefore, in order to prevent personal injury or fire arising from failure, please take safety measures such as complying with the derating characteristics, implementing redundant and fire prevention designs, and utilizing backups and fail-safe procedures. ROHM shall have no responsibility for any damages arising out of the use of our Products beyond the rating specified by ROHM.
- 4) Examples of application circuits, circuit constants and any other information contained herein are provided only to illustrate the standard usage and operations of the Products. The peripheral conditions must be taken into account when designing circuits for mass production.
- 5) The technical information specified herein is intended only to show the typical functions of and examples of application circuits for the Products. ROHM does not grant you, explicitly or implicitly, any license to use or exercise intellectual property or other rights held by ROHM or any other parties. ROHM shall have no responsibility whatsoever for any dispute arising out of the use of such technical information.
- 6) The Products are intended for use in general electronic equipment (i.e. AV/OA devices, communication, consumer systems, gaming/entertainment sets) as well as the applications indicated in this document.
- 7) The Products specified in this document are not designed to be radiation tolerant.
- 8) For use of our Products in applications requiring a high degree of reliability (as exemplified below), please contact and consult with a ROHM representative : transportation equipment (i.e. cars, ships, trains), primary communication equipment, traffic lights, fire/crime prevention, safety equipment, medical systems, servers, solar cells, and power transmission systems.
- 9) Do not use our Products in applications requiring extremely high reliability, such as aerospace equipment, nuclear power control systems, and submarine repeaters.
- 10) ROHM shall have no responsibility for any damages or injury arising from non-compliance with the recommended usage conditions and specifications contained herein.
- 11) ROHM has used reasonable care to ensure the accuracy of the information contained in this document. However, ROHM does not warrants that such information is error-free, and ROHM shall have no responsibility for any damages arising from any inaccuracy or misprint of such information.
- 12) Please use the Products in accordance with any applicable environmental laws and regulations, such as the RoHS Directive. For more details, including RoHS compatibility, please contact a ROHM sales office. ROHM shall have no responsibility for any damages or losses resulting non-compliance with any applicable laws or regulations.
- 13) When providing our Products and technologies contained in this document to other countries, you must abide by the procedures and provisions stipulated in all applicable export laws and regulations, including without limitation the US Export Administration Regulations and the Foreign Exchange and Foreign Trade Act.
- 14) This document, in part or in whole, may not be reprinted or reproduced without prior consent of ROHM.



Thank you for your accessing to ROHM product informations.
More detail product informations and catalogs are available, please contact us.

ROHM Customer Support System

<http://www.rohm.com/contact/>